

Supporting Information

Stable Perovskite Solar Cells via exfoliated graphite as an ion diffusion-blocking layer

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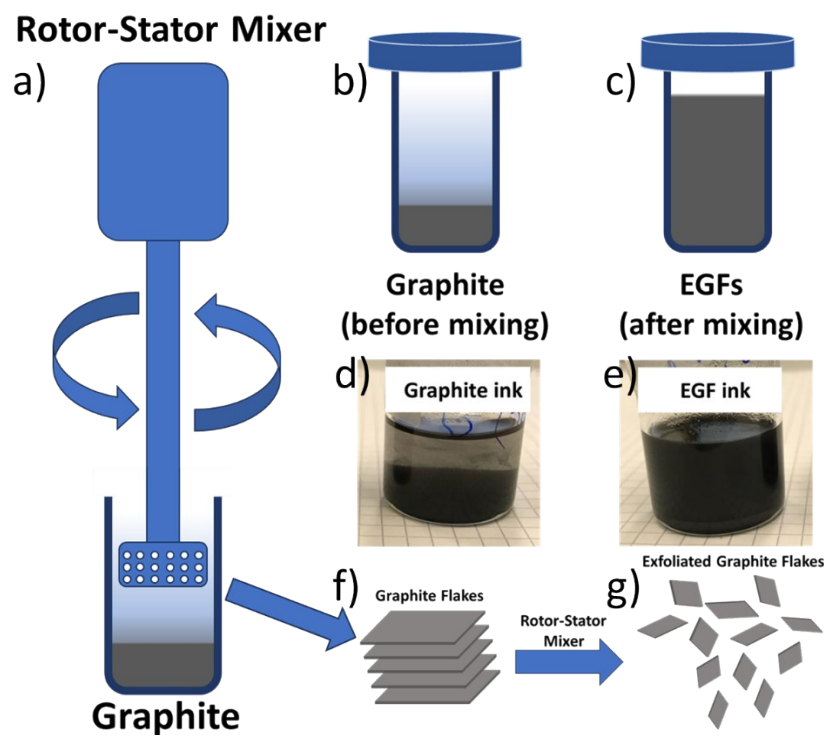


Figure S1. (a) Schematic illustration of RSM exfoliation/fragmentation process. Schematic illustration and images of the graphite flakes and inks (b,d,f) before and (c,e,g) after the RMS process application to the precursor dispersion.

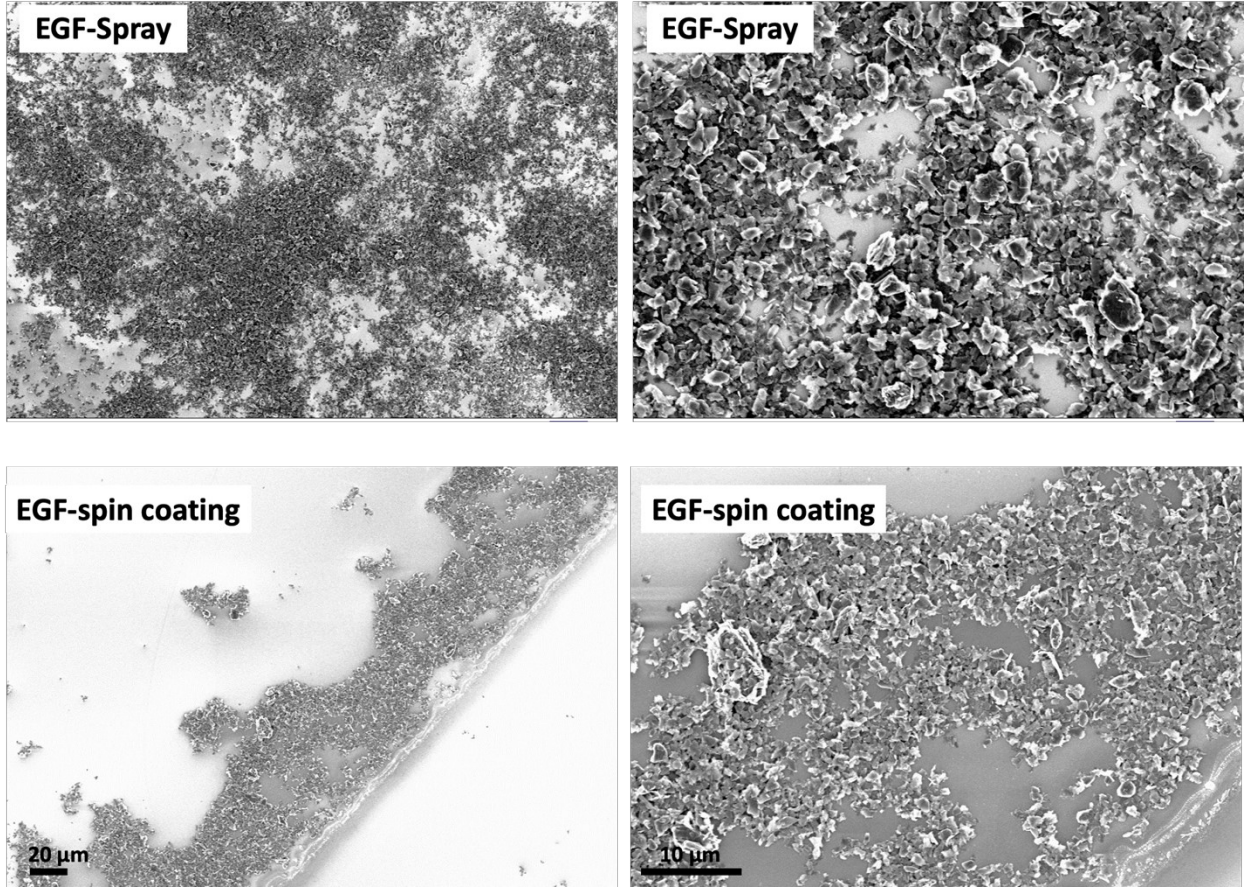


Figure S2. Top-view SEM images comparing the surface coverage of graphene flakes deposited through spray- and spin-coating techniques.

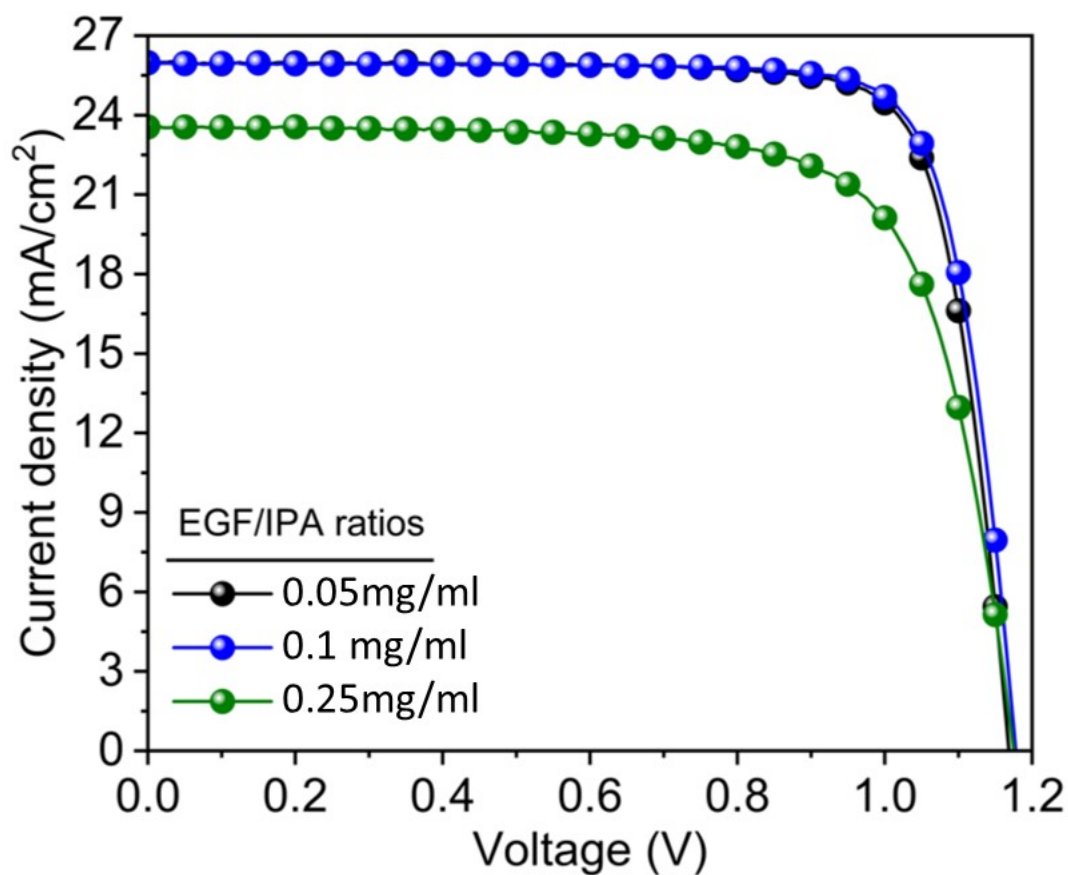


Figure S3. *J-V* characteristics curves using different EGF/ethanol ratio solutions.

Table S1. PV parameters extracted from Figure S6

| EGF to IPA ratio | V _{oc} (V) | J _{sc} (mA/cm ²) | FF(%) | PCE(%) | |
|------------------|---------------------|---------------------------------------|-------|--------|--------|
| 0.05 mg/ml | 1.165 | 25.97 | 81.1 | 24.54 | |
| 0.1 mg/ml | 1.178 | 25.98 | 81.4 | 25.0 | Target |
| 0.25 mg/ml | 1.174 | 24.15 | 73.5 | 20.84 | |

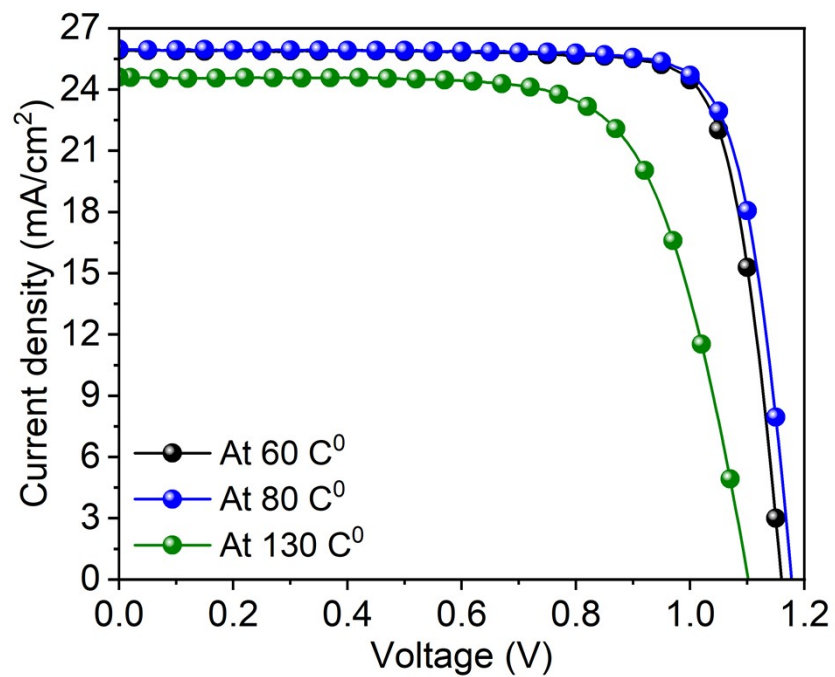


Figure S4. J - V characteristics curves at different preparation temperatures.

Table S2. PV parameters extracted from Figure S7

| Temperature | V_{oc} (V) | J_{sc} (mA/cm ²) | FF(%) | PCE(%) | |
|-------------|--------------|--------------------------------|-------|--------|--------|
| 60 | 1.153 | 25.92 | 82.0 | 24.51 | |
| 80 | 1.178 | 25.98 | 81.4 | 25.0 | Target |
| 130 | 1.090 | 24.60 | 71.3 | 19.12 | |

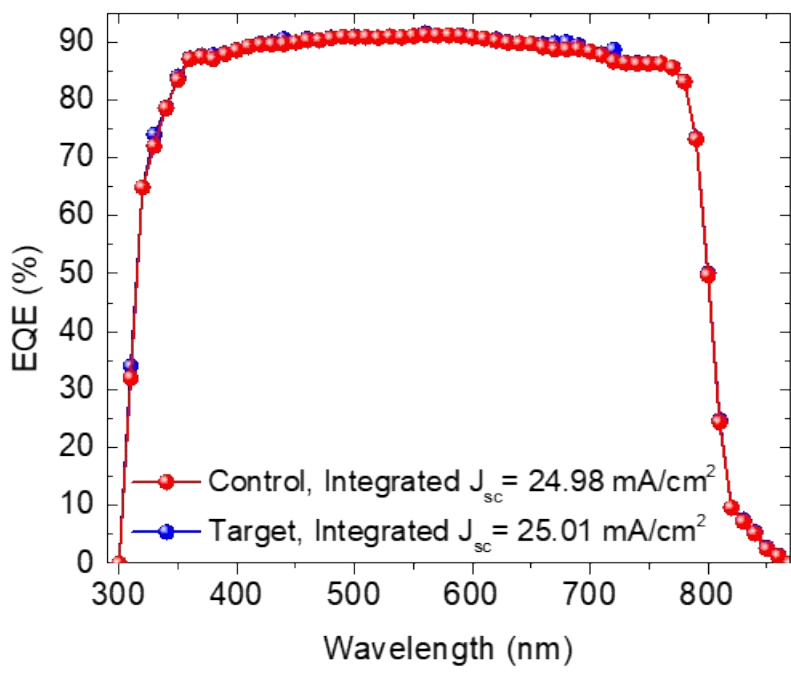


Figure S5. EQE spectra and photocurrent integrated over the standard AM 1.5G solar spectrum

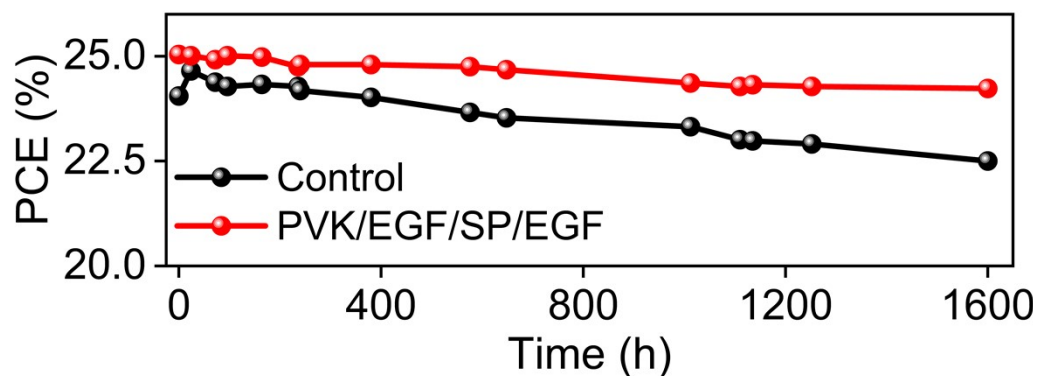


Figure S6. Shelf stability at RT and under ~8% RH of the control and target devices using Spiro-OMeTAD as HTL.

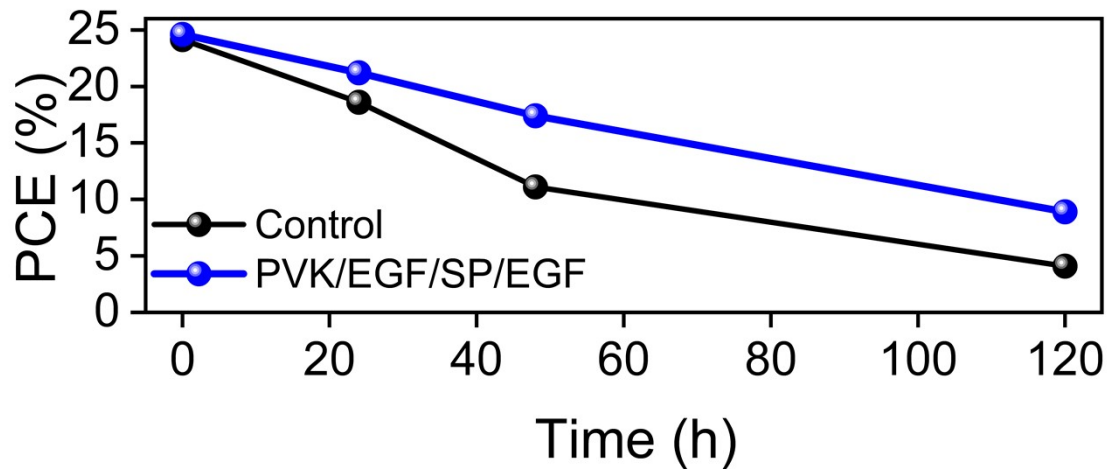


Figure S7. Shelf stability at 80 °C and ~75% RH of the control and target samples using Spiro-OMeTAD as the HTL.

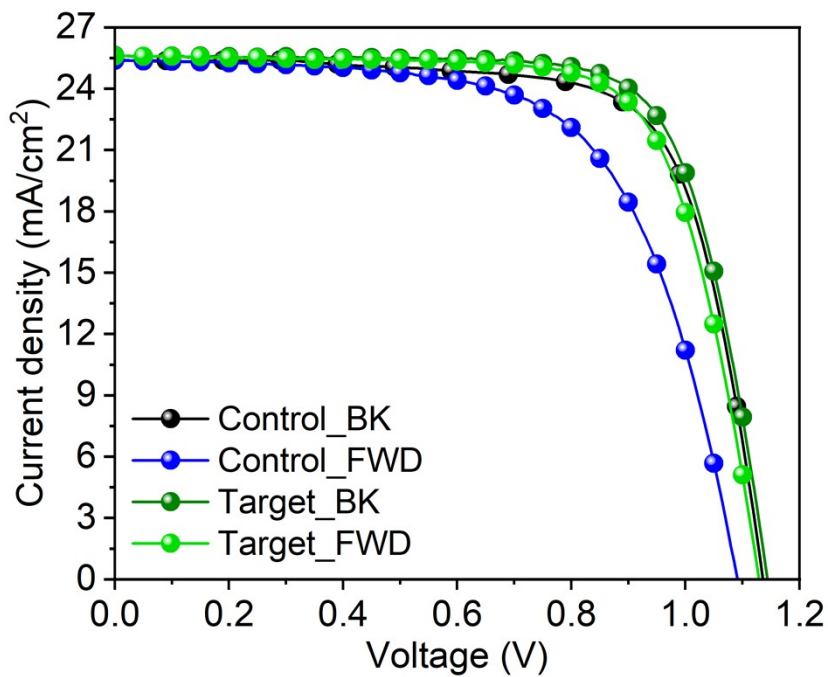


Figure S8. $J-V$ results for devices using PTAA as HTL for control and target devices.

Table S3. PV parameters extracted from Figure S10

| | V_{oc} (V) | J_{sc} (mA/cm ²) | FF(%) | PCE(%) | |
|-----|--------------|--------------------------------|-------|--------|---------|
| Bk | 1.132 | 25.41 | 72.50 | 20.86 | control |
| FWD | 1.070 | 25.39 | 63.70 | 17.31 | control |
| Bk | 1.142 | 25.62 | 74.4 | 21.77 | Target |
| FWD | 1.121 | 25.61 | 73.3 | 21.04 | Target |

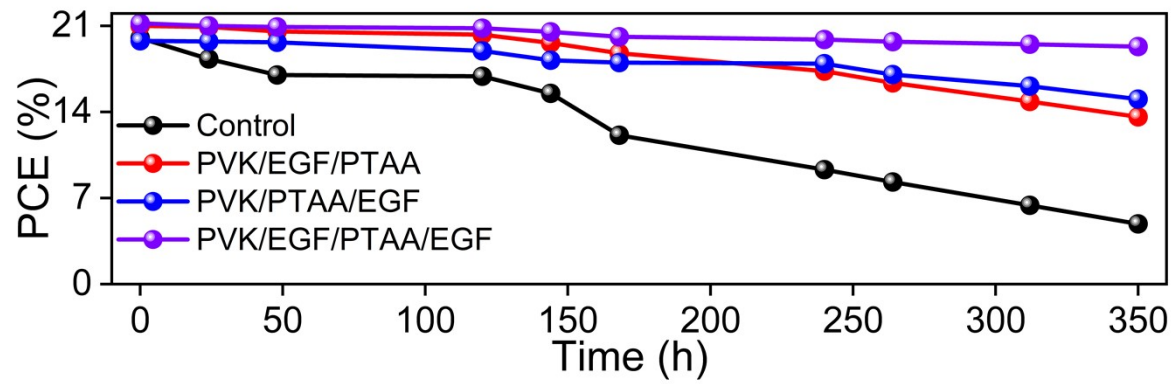


Figure S9. Shelf stability at RT and ~8% RH of control and target devices using PTAA as HTL.